

# SANYO Semiconductors DATA SHEET

# 2SD2600 — NPN Triple Diffused Planar Silicon Darlington Transistor Driver Applications

## **Applications**

· Motor drivers, printer hammer drivers, relay drivers, voltage regulator control.

#### **Features**

- · High DC current gain.
- · Large current capacity and wide ASO.

## **Specifications**

## Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		110	V
Collector-to-Emitter Voltage	VCEO		100	V
Emitter-to-Base Voltage	VEBO		6	V
Collector Current	IC		8	Α
Collector Current (Pulse)	ICP		12	Α
Collector Dissipation	PC	Tc=25°C	35	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

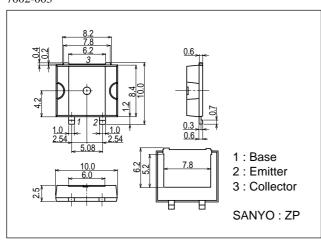
### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	ICBO	VCB=80V, IE=0A			0.1	mA
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =5V, I <sub>C</sub> =0A			3.0	mA
DC Current Gain	hFE	V <sub>CE</sub> =3V, I <sub>C</sub> =4A	1500	4000		
Gain-Bandwidth Product	fŢ	VCE=5V, IC=4A		20		MHz
Collector-to-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> =4A, I <sub>B</sub> =8mA		0.9	1.5	V
Base-to-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> =4A, I <sub>B</sub> =8mA			2.0	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=5mA, IE=0A	110			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=50mA, RBE=∞	100			V
Turn-ON Time	ton	See specified test circuit.		0.6		μs
Storage Time	tstg	See specified test circuit.		4.8		μs
Fall Time	t <sub>f</sub>	See specified test circuit.		1.6		μs

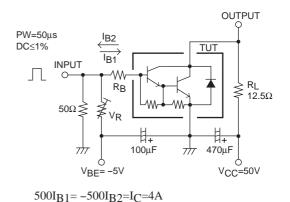
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## **Package Dimensions**

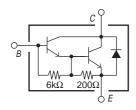
unit : mm (typ) 7002-003

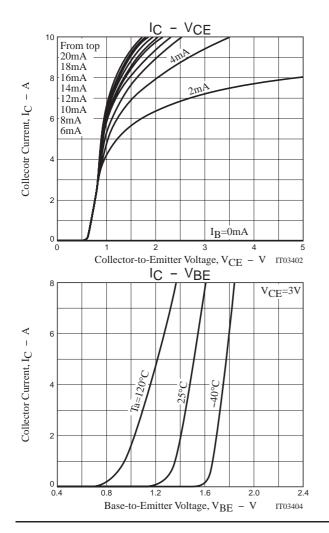


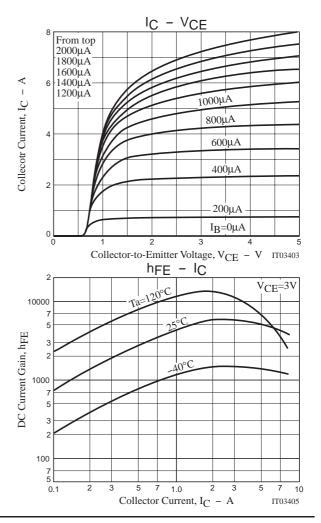
## **Switching Time Test Circuit**



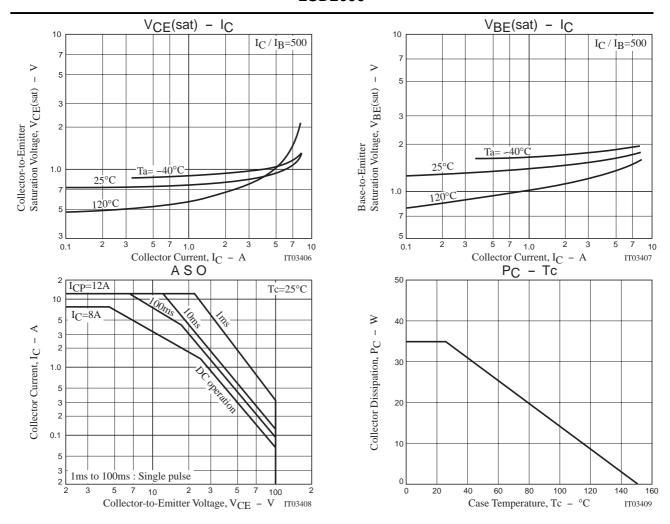
## **Electrical Connection**







### 2SD2600



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